

## 1500V 9A 2.9Ω N-ch Power MOSFET

# **Description**

WMOS D1 is Wayon's 1<sup>st</sup> generation VDMOS family that is dramatic reduction in on-resistance and ultra-low gate charge for applications requiring high power density and high efficiency. And it is very robust and RoHS compliant.

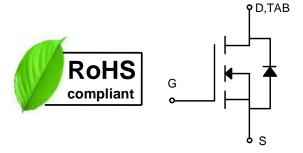


### **Features**

- $R_{DS(on)}=2.9\Omega@V_{GS}=10V$
- 100% avalanche tested
- RoHS Compliant

# **Applications**

- SMPS
- Charger
- DC-DC



## **Absolute Maximum Ratings** (Tc=25℃)

Parameter	Symbol	WMJ9N150D1	Unit
Drain-source voltage	V <sub>DSS</sub>	1500	V
Gate-source voltage	V <sub>GS</sub>	±30	V
Continuous drain current	I <sub>D</sub>	9	А
Pulsed drain current <sup>1</sup>	I <sub>DM</sub>	36	А
Avalanche energy, single pulse <sup>2</sup>	E <sub>AS</sub>	245	mJ
Power dissipation	PD	320	W
Derate above 25°C		2.56	W/°C
Operating junction temperature	Tj	-55~150	℃
Storage temperature	T <sub>stg</sub>	-55~150	℃
Continuous diode forward current	Is	9	А
Diode pulse current	I <sub>Spulse</sub> <sup>1</sup>	36	А

### **Thermal Characteristic**

Thermal resistance,junction-to-case	Rejc	0.39	°C/W
Thermal resistance,junction-to-ambient	RθJA	55	°C/W





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Drain-source break down voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0V	Tc=25°C	1500	ı	-	V
Gate threshold voltage	V <sub>GS(th)</sub>	I <sub>D</sub> =250μA, V <sub>DS</sub> =V <sub>GS</sub>	TJ=25°C	2.5	ı	4.5	V
Drain source leakage ourrent	I <sub>DSS</sub>	V <sub>DS</sub> =1500V, V <sub>GS</sub> =0V	TJ=25°C	-	-	1	μΑ
Drain-source leakage current		V <sub>DS</sub> =1200V, V <sub>GS</sub> =0V	TJ=125°C	-	-	100	μΑ
Gate-source leakage current,forward	IGSSF	V <sub>DS</sub> =0V, V <sub>GS</sub> =30V	TJ=25°C	-	-	100	nA
Gate-source leakage current,reverse	Igssr	V <sub>DS</sub> =0V, V <sub>GS</sub> =-30V	TJ=25°C	-	-	-100	nA
Drain-source on-state resistance <sup>3</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =4.5A	TJ=25°C	-	2.9	4.2	Ω
Transconductance <sup>3</sup>	Gfs	V <sub>DS</sub> =10V	TJ=25°C	-	8.3	-	S

# Dynamic Characteristics of MOSFET $(T_C=25^{\circ}C)$

Dynamic Characteristics of MOSFET (10=25 C)		Min.	Тур.	Max.		
Input capacitance	Ciss	f=1MHz, V <sub>DS</sub> =25V,	-	3555	-	pF
Output capacitance	Coss	V <sub>GS</sub> =0V	-	189	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	V <sub>GS</sub> =UV		24	-	pF
Gate to source charge	Qgs	V <sub>DD</sub> =600V	-	18	-	nC
78Gate to drain charge	Qgd	I <sub>D</sub> =9A	-	28.8	-	nC
Total gate charge	Qg	V <sub>GS</sub> = 0 to10V	-	85.2	-	nC

## Switching Characteristics of MOSFET (Tc=25°C)

_			Min.	Typ.	Max.	
Turn-on delay time	t <sub>d on</sub>		-	58	-	ns
Rise time	tr	V <sub>DS</sub> =600V, I <sub>D</sub> =9A,	-	71	-	ns
Turn-off delay time	t <sub>d off</sub>	$R_G=25\Omega$ , $V_{GS}=0$ to $10V$	-	228	-	ns
Fall time	t <sub>f</sub>		-	68	-	ns

# Characteristics of Body Diode (Tc=25℃)

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Forward voltage	V <sub>SD</sub>	I <sub>SD</sub> =9A, V <sub>GS</sub> =0V	-	1	1.3	V
Reverse recovery time	t <sub>rr</sub>	V <sub>DS</sub> =600V, I <sub>S</sub> =9A,	-	540	-	ns
Reverse recovery current	Irr	V <sub>GS</sub> =10V	-	31.9	-	Α
Recovery charge	Qrr	di/dt=100A/µs	-	8.6	-	μC

#### Notes:

- 1. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$  =150°C.
- 2. The E\_{AS} data shows Max. rating . The test condition is V\_DD =50V, V\_GS =10V, L=10mH, I\_{AS} =7A,Tc=25 ^{\circ}C .
- 3. The data tested by pulsed , pulse width  $\leq 300 \mu s$  , duty cycle  $\leq 2\%.$



#### TYPICAL CHARACTERISTICS

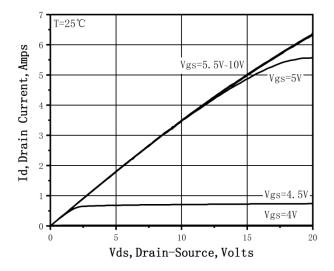


Figure 1.On-Region Characteristics

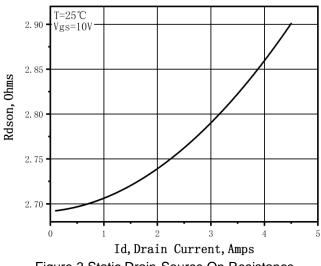


Figure 3.Static Drain-Source On Resistance

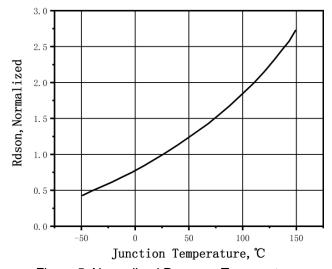


Figure 5. Normalized R<sub>DS(on)</sub> vs.Temperature

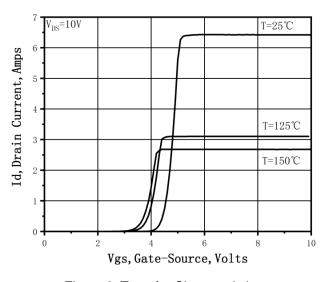


Figure 2. Transfer Characteristics

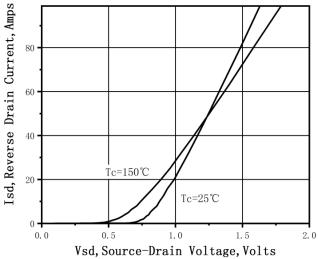


Figure 4. Typical Body Diode Transfer Characteristics

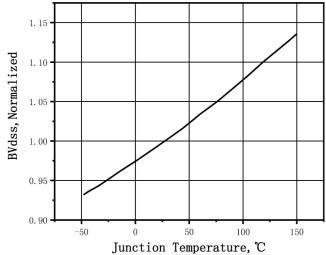


Figure 6. Normalized BV<sub>DSS</sub> vs.Temperature



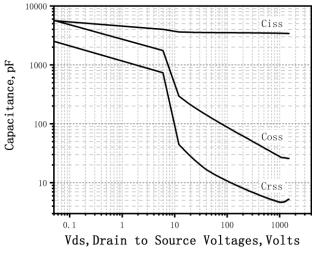


Figure 7. Capacitance Characteristics

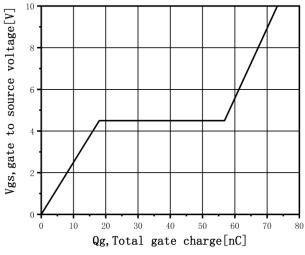


Figure 8. Gate Charge Characteristics

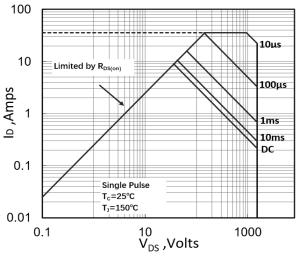


Figure 9. Maximum Safe Operating Area (TO-247)

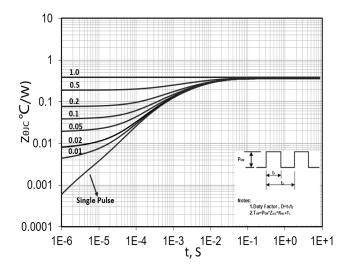
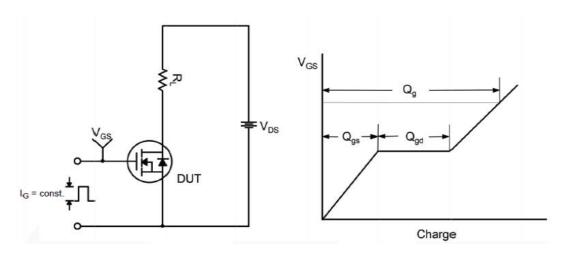


Figure 10. Transient Thermal Response Curve (TO-247)

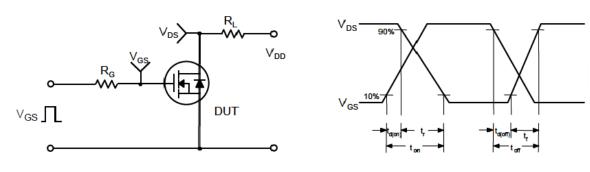


### **Test Circuit**

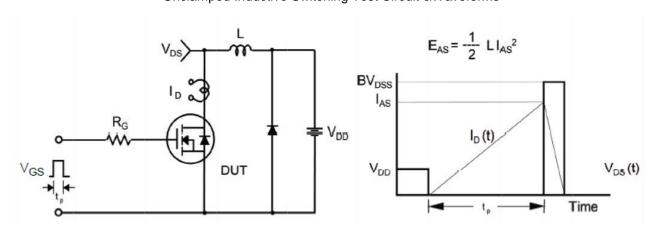
# Gate Charge Test Circuit &Waveform



## Switching Test Circuit &Waveforms

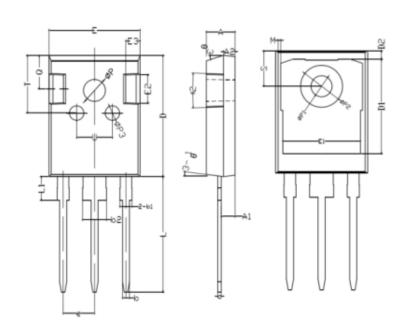


## Unclamped Inductive Switching Test Circuit &Waveforms





### **Mechanical Dimensions for TO-247**



#### **COMMON DIMENSIONS**

SYMBOL	M	М
STIVIDOL	MIN	MAX
Α	4.80	5.20
A1	2.21	2.59
A2	1.85	2.15
b	1.11	1.36
b1	1.91	2.25
b2	2.91	3.25
С	0.51	0.75
D	20.70	21.30
D1	16.25	16.85
Е	15.50	16.10
E1	13.00	13.60
E2	4.80	5.20
E3	2.30	2.70
е	5.40	5.48
L	19.62	20.22
L1	-	4.30
ØР	3.40	3.80
ØP2	6.90	7.30
S	6.05	6.25

## **Ordering Information**

Part	Package	Marking	Packing method	
WMJ9N150D1	TO-247	WMJ9N150D1	Tube	

## **Contact Information**

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WAYON website: http://www.way-on.com

For additional information, please contact your local Sales Representative.

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## **Product Specification Statement**

1. The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

2. The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. WAYON shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and WAYON assumes no responsibility for the application of the product.

3.WAYON strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, WAYON cannot guarantee that the information provided in the product specification is entirely accurate and error-free. WAYON shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications. WAYON reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with WAYON to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult WAYON in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

4.Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

5. The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. WAYON shall assume no responsibility for any consequences resulting from such usage.

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